## **ABSOLUTE MAXIMUM RATINGS**

Voltages Referenced to GND

V+, IN	0.3V to +6V
COM, NC, NO (Note 1)	0.3V to (V+ + 0.3V)
Continuous Current NO, NC to COM	±200mÁ
Peak Current NO, NC to COM	
(pulsed at 1ms, 10% duty cycle max)	±400mA

Continuous Power Dissipation	
6-Pin SOT23 (derate 7.1mW/°C abov	e +70°C)571mW
6-Pin Thin SOT23 (derate 6.25mW/°C	above +70°C)500mW
Operating Temperature Range	
MAX462_E_T	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C

Note 1: Signals on NC, NO, and COM exceeding V+ or GND are clamped by internal diodes.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = +5V  $\pm$ 10%, GND = 0, V<sub>INH</sub> = 2.4V, V<sub>INL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	МАХ	UNITS	
ANALOG SWITCH								
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>			0		V+	V	
On-Resistance	Ron	V+ = 4.5V, V <sub>NO</sub> or V <sub>NC</sub> = 3.5V, I <sub>COM</sub> = 100mA	$T_A = +25^{\circ}C$		0.65	1	Ω	
On nesistance	NON		$T_A = T_{MIN}$ to $T_{MAX}$			1.2	22	
On-Resistance Match Between	ΔRon	V+ = 4.5V, I <sub>COM</sub> = 100mA,	$T_A = +25^{\circ}C$		0.06	0.12	Ω	
Channels (Note 4)		$V_{NO} \text{ or } V_{NC} = 3.5 V$	$T_A = T_{MIN}$ to $T_{MAX}$			0.15	_ 12	
On-Resistance Flatness	RFLAT(ON)	$V + = 4.5V; I_{COM} = 100mA;$	$T_A = +25^{\circ}C$		0.08	0.12	- Ω	
(Note 5)	TFLAT(ON)	$V_{NO} \text{ or } V_{NC} = 0, 1V, 2V$	$T_A = T_{MIN}$ to $T_{MAX}$			0.15		
NO or NC Off-Leakage	INO(OFF),	V+ = 5.5V; V <sub>COM</sub> = 1V, 4.5V;	$T_A = +25^{\circ}C$	-2	0.01	2	nA	
Current	INC(OFF)	$V_{NO} \text{ or } V_{NC} = 4.5V, 1V$	$T_A = T_{MIN}$ to $T_{MAX}$	-20		20		
COM On-Leakage Current		$V + = 5.5V; V_{COM} = 1V, 4.5V;$	T <sub>A</sub> = +25°C	-4	0.3	4	– nA	
	ICOM(ON)	$V_{NO}$ or $V_{NC} = 1V$ , 4.5V, or floating	$T_A = T_{MIN}$ to $T_{MAX}$	-40		40		
Overcurrent-Protection Current Threshold		T <sub>A</sub> = +25°C			1.2		A	
DYNAMIC								
Turn-On Time	ton	$V_{NO}$ or $V_{NC}$ = 3V, Figure 2	$T_A = +25^{\circ}C$		40	50	ns	
Tum-On Time			$T_A = T_{MIN}$ to $T_{MAX}$			60		
Turn-Off Time	tOFF	$V_{NO}$ or $V_{NC}$ = 3V, Figure 2	$T_A = +25^{\circ}C$		40	50		
Turn-Oli Time			$T_A = T_{MIN}$ to $T_{MAX}$			60	ns	
Break-Before-Make Delay	taav		$T_A = +25^{\circ}C$	1	20			
(Note 6)	t <sup>BBM</sup>	MAX4624 only, Figure 3a	$T_A = T_{MIN}$ to $T_{MAX}$	1			ns	
Make-Before-Break Delay	ta 100	MAY400E anhy Figure 01-	$T_A = +25^{\circ}C$	1	6			
Note 6)	INIRR	MAX4625 only, Figure 3b	$T_A = T_{MIN}$ to $T_{MAX}$	1			ns	

## ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V + = +5V \pm 10\%, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$  to T<sub>MAX</sub>, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Charge Injection	Q	$C_L = 1.0nF, V_{GEN} = 0, R_{GEN} = 0, T_A = +25^{\circ}C,$ Figure 4 65			рС	
Off-Isolation (Note 7)	OIRR	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , $T_A = +25^{\circ}C$ , Figure 5 -57				dB
Crosstalk (Note 8)		$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , $T_A = +25^{\circ}C$ , Figure 5	-57		dB	
NC or NO Off-Capacitance	COFF	$f = 1MHz$ , $T_A = +25^{\circ}C$ , Figure 6		32		pF
COM On-Capacitance	C <sub>COM</sub> (ON)	$f = 1MHz$ , $T_A = +25^{\circ}C$ , Figure 6		100		pF
LOGIC INPUT	-					
Input Voltage Low	VINL				0.8	V
Input Voltage High	VINH		2.4			V
Logic Input Current	lin		-1		1	μA
SUPPLY						
Power-Supply Range	V+	1.8 5.		5.5	V	
Positive Supply Current	I+	V+ = 5.5V, VIN = 0 or V+ 10		10	μA	

# ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +2.7V to +3.6V, GND = 0, V<sub>INH</sub> = 2.0V, V<sub>INL</sub> = 0.6V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH	L						
Analog Signal Range	VCOM, VNO, VNC			0		V+	V
On-Resistance	Pou	$V_{+} = 2.7V,$	$T_A = +25^{\circ}C$		1.2	2.0	- Ω
On-nesistance	R <sub>ON</sub>	$V_{NO} \text{ or } V_{NC} = 1.5V,$ $I_{COM} = 100mA$	$T_A = T_{MIN}$ to $T_{MAX}$			2.5	
On-Resistance Flatness (Note 6)	R <sub>FLAT</sub> (ON)	V+ = 2.7V; $I_{COM}$ = 100mA; $V_{NO}$ or $V_{NC}$ = 0, 0.75V, 1.5V; $T_{A}$ = +25°C			0.25		Ω
DYNAMIC				1			1
Turn-On Time	ton	$V_{NO} \text{ or } V_{NC} = 1.5V,$ Figure 2	$T_A = +25^{\circ}C$		65	80	ns
			$T_A = T_{MIN}$ to $T_{MAX}$			100	
Turn-Off Time	torr	$V_{NO}$ or $V_{NC} = 1.5V$ , Figure 2	$T_A = +25^{\circ}C$		62	80	ns
Turn-Off Time tOFF	UFF		$T_A = T_{MIN}$ to $T_{MAX}$			100	
Break-Before-Make Time Delay (Note 4)	t <sub>BBM</sub>	MAX4624 only, Figure 3a		1	40		ns
Make-Before-Break Time Delay (Note 4)	tMBB	MAX4625 only, Figure 3b		1	8		ns
Charge Injection	Q	C <sub>L</sub> = 1.0nF, Figure 4, V <sub>GEN</sub> = 0, R <sub>GEN</sub> = 0, T <sub>A</sub> = +25°C			40		рС

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### ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = +2.7V to +3.6V, GND = 0,  $V_{INH}$  = 2.0V,  $V_{INL}$  = 0.6V,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
LOGIC INPUT			·			
Input Voltage Low	VINL				0.6	V
Input Voltage High	Vinh		2.0			V
Logic Input Current	I <sub>IN</sub>		-1		1	μA
SUPPLY						
Positive Supply Current	I+	$V + = 3.6V, V_{IN} = 0 \text{ or } V +$			10	μA

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

**Note 3:** SOT-packaged parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation.

Note 4:  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 5:** Flatness is defined as the difference between the maximum and minimum values of on-resistance as measured over the specified analog signal range.

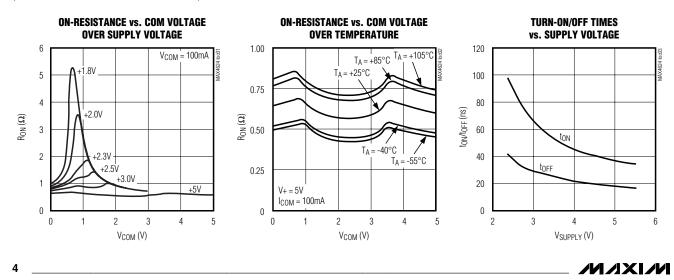
Note 6: Guaranteed by design.

Note 7: Off-Isolation = 20log10 [VCOM / (VNC or VNO)], VCOM = output, VNC or VNO = input to off switch.

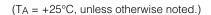
Note 8: Between the two switches.

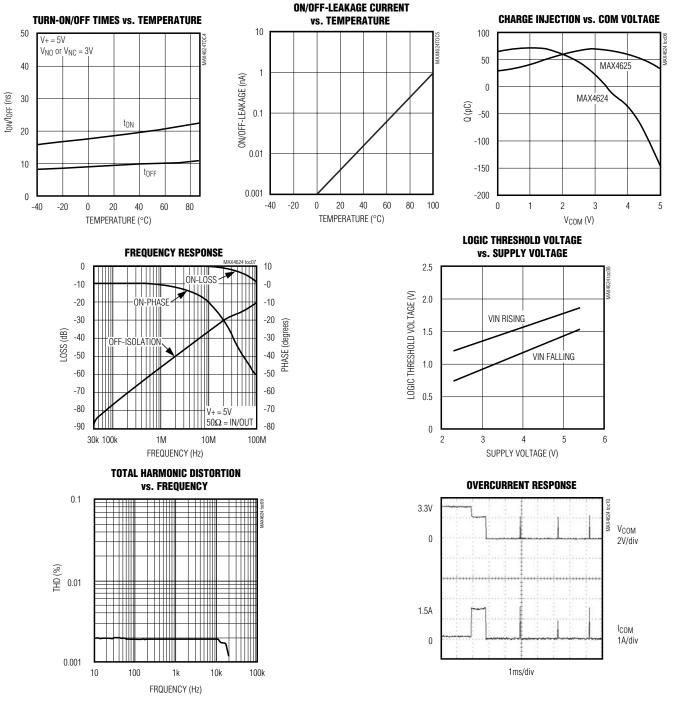
# **Typical Operating Characteristics**

#### $(T_A = +25^{\circ}C, unless otherwise noted.)$



# **Typical Operating Characteristics (continued)**





5



///XI//

**Pin Description** 

PIN	NAME	FUNCTION
1	IN	Digital Control Input
2	V+	Positive Supply Voltage Input
3	GND	Ground
4	NC	Analog Switch—Normally Closed
5	СОМ	Analog Switch—Common
6	NO	Analog Switch—Normally Open

## **Detailed Description**

The MAX4624/MAX4625 are low-on-resistance (RoN), low-voltage, single-pole/double-throw (SPDT) analog switches that operate from a +1.8V to +5.5V supply. The MAX4624 has break-before-make switching, and the MAX4625 has make-before-break switching. These devices also have fast switching speeds ( $t_{ON}$  = 50ns max, toFF = 50ns max).

When powered from a +5V supply, their 1 $\Omega$  max R<sub>ON</sub> allows high continuous currents to be switched in a variety of applications. In an overcurrent condition, these switches provide both current-limit and thermal-shutdown protection.

#### **Current-Limit Protection**

The MAX4624/MAX4625 feature current-limit protection circuitry. When the voltage drop across the on switch reaches 0.6V typ, the internal circuitry activates. The current limit is not instantaneous, but rather integrates

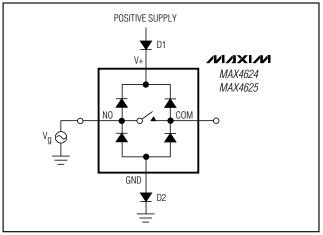


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

over time, so current limiting will not activate when the switch output charges a small  $0.1\mu$ F capacitor. For sustained overload conditions, the switch turns off (opens). The switch turns on after 5ms. If the overload persists, the switch cycles off and on to produce a pulsed output. A direct short circuit will be detected immediately, and the switch will pulse on for 1µs, then remain off for 5ms.

### **Applications Information**

#### **Logic Inputs**

The MAX4624/MAX4625 logic inputs can be driven up to +5.5V regardless of the supply voltage. For example, with a +3.3V supply, IN may be driven low to 0V and high to 5.5V. Driving IN Rail-to-Rail<sup>®</sup> minimizes power consumption.

#### **Analog Signal Levels**

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in on-resistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO, NC, and COM pins can be used as either inputs or outputs.

#### Power-Supply Sequencing and Overvoltage Protection

#### Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices.

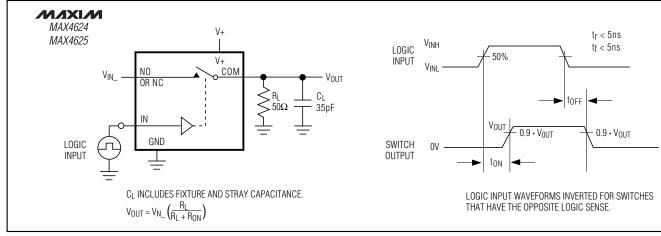
Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited. If this sequencing is not possible, and if the analog inputs are not current limited to <20mA, add

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6

a small-signal diode (D1) as shown in Figure 1. If the analog signal can dip below GND, add D2. Adding protection diodes reduces the analog range to a diode drop (about 0.7V) below V+ (for D1), and a diode drop above ground (for D2). On-resistance increases slightly at low supply voltages. Maximum supply voltage (V+) must not exceed +6V.

Adding protection diode D2 causes the logic threshold to be shifted relative to GND. TTL compatibility is not guaranteed when D2 is added. Protection diodes D1 and D2 also protect against some overvoltage situations. With Figure 1's circuit, if the supply voltage is below the absolute maximum rating, and if a fault voltage up to the absolute maximum rating is applied to an analog signal pin, no damage will result.



# Test Circuits/Timing Diagrams

Figure 2. Switching Time

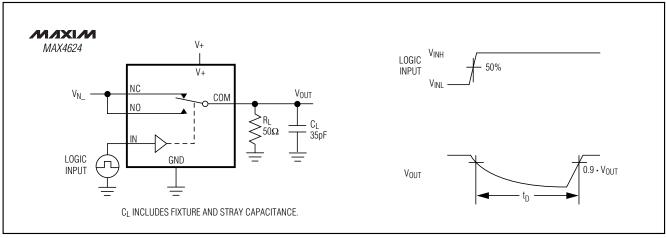


Figure 3a. Break-Before-Make Interval (MAX4624 only)

## Test Circuits/Timing Diagrams (continued)

MXXM

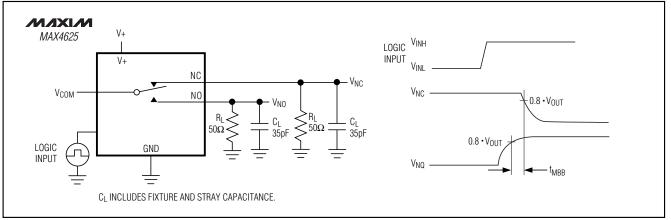


Figure 3b. Make-Before-Break Interval (MAX4625 only)

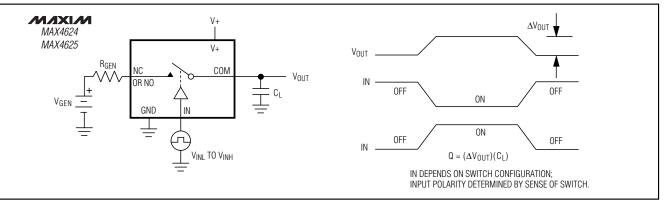


Figure 4. Charge Injection

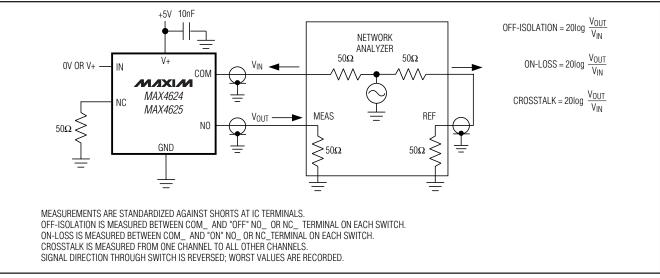


Figure 5. On-Loss, Off-Isolation, and Crosstalk

# \_Chip Information

**TRANSISTOR COUNT: 186** 

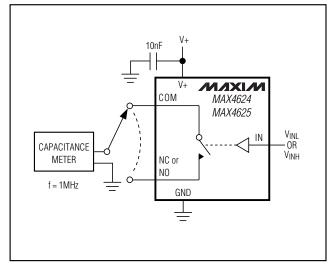
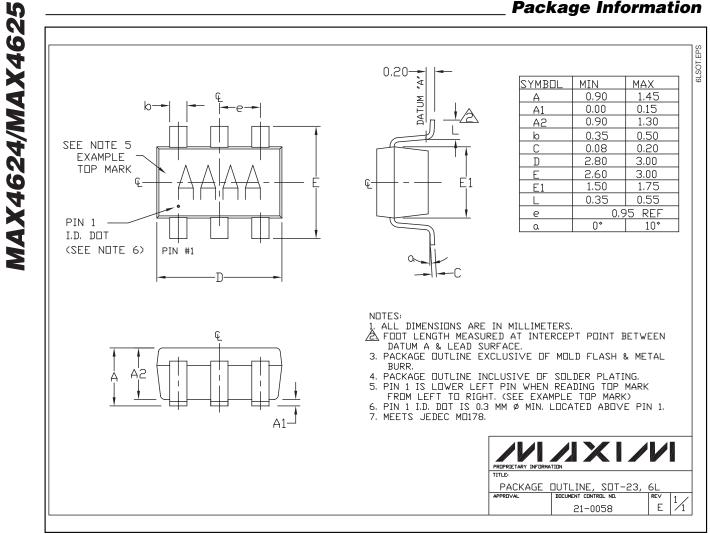
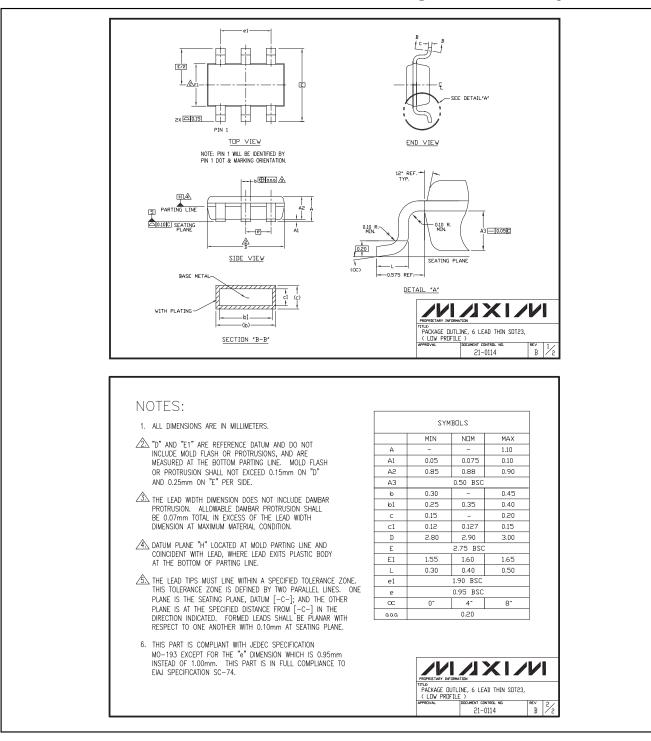


Figure 6. Channel Off/On-Capacitance



### Package Information (continued)



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MAX4624/MAX4625